

“Investigation of strain and doping on the electronic properties of single layers of C₃N₄ and C₃N₂: a first principles study”. Bafekry A, Nguyen C V, Goudarzi A, Ghergherehchi M, Shafieirad M, Rsc Advances **10**, 27743 (2020). <http://doi.org/10.1039/D0RA04463F>